

RGPZ10BM40FH

430V 20A Ignition IGBT

BV _{CES}	430±30V
I _C	20A
V _{CE(sat) (Typ.)}	1.6V
E _{AS}	250mJ

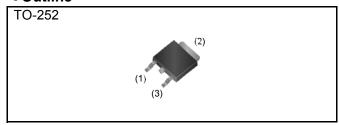
Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Self-Clamped Inductive Switching Energy
- 3) Built in Gate-Emitter Protection Diode
- 4) Qualified to AEC-Q101
- 5) Pb free Lead Plating; RoHS Compliant

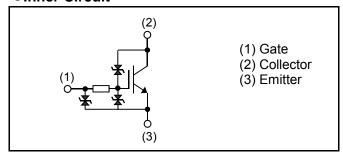
Applications

Ignition Coil Driver Circuits
Solenoid Driver Circuits

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Taping
	Reel Size (mm)	330
Typo	Tape Width (mm)	16
Туре	Basic Ordering Unit (pcs)	2,500
	Packing Code	TL
Marking		RGPZ10BM40

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Collector - Emitter Voltage	V _{CES}	460	V	
Emitter-Collector Voltage (V _{GE} = 0\	/)	V _{EC}	25	V
Gate - Emitter Voltage	V_{GE}	±10	V	
Collector Current	I _C	20	А	
Avalanche Energy (Single Pulse)	T _j = 25°C	E _{AS}	250	mJ
	T _j = 150°C	E _{AS} *2	150	mJ
Power Dissipation	P _D	107	W	
Operating Junction Temperature	T _j	-40 to +175	°C	
Storage Temperature	T _{stg}	-55 to +175	°C	

●Thermal Resistance

Parameter	Symbol	Values			Unit
r ai ai iletei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance Junction - Case	$R_{\theta(j-c)}$	-	-	1.40	°C/W

ullet Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
		$I_C = 2mA$, $V_{GE} = 0V$				
Collector - Emitter Breakdown Voltage	BV_CES	T _j = 25°C	400	430	460	V
		$T_j = -40 \text{ to } 175^{\circ}\text{C}^{*2}$	395	-	465	V
Emitter - Collector Breakdown Voltage	BV_{EC}	$I_{C} = -10 \text{mA}, V_{GE} = 0 \text{V}$	25	35	1	V
Gate - Emitter Breakdown Voltage	BV_GES	$I_G = \pm 5$ mA, $V_{CE} = 0$ V	±12	-	±17	٧
	I _{CES}	$V_{CE} = 300V, V_{GE} = 0V$				
Collector Cut - off Current		T _j = 25°C	-	-	7	μΑ
		$T_j = 150^{\circ}C^{*2}$	-	-	100	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 10V, V_{CE} = 0V$	-	-	±15	μΑ
Gate - Emitter Threshold Voltage		$V_{CE} = 5V, I_{C} = 10mA$				
	$V_{GE(th)}$	T _j = 25°C	1.3	1.7	2.1	V
		T _j = 150°C	-	1.3	-	V
Collector - Emitter Saturation Voltage		$I_{\rm C}$ = 10A, $V_{\rm GE}$ = 5V				
	$V_{\text{CE(sat)}}$	T _j = 25°C	-	1.60	2.00	V
		T _j = 150°C	-	1.80	-	V

●Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Cymphal	Conditions	Values			Linit
i didilicici	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Saturation	V _{CE(sat)}	$I_C = 4A, V_{GE} = 4.5V$ $T_j = 25^{\circ}C$	-	1.17	1.50	V
Voltage		$T_j = 150$ °C	-	1.13	-	V
Collector - Emitter Saturation		$I_{\rm C} = 10 \text{A}, V_{\rm GE} = 4 \text{V}$		4.70	0.40	
Voltage	V _{CE(sat)}	$T_j = 25^{\circ}C$ $T_j = 150^{\circ}C$	-	1.70 1.90	2.10	V V
Input Capacitance	C _{ies}	V _{CE} = 10V	-	1000	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	175	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	ı	55	-	
Total Gate Charge	Q_g	$V_{CE} = 15V, I_{C} = 10A,$ $V_{GE} = 5V$	-	14	-	nC
Turn - on Delay Time*1,*2	t _{d(on)}		0.09	0.17	0.50	
Rise Time*1,*2	t _r	$I_C = 8A, V_{CC} = 300V,$	0.10	0.18	0.50	μs
Turn - off Delay Time*1,*2	$t_{d(off)}$	V_{GE} = 5V, R_{G} = 100 Ω , L=5mH, T_{J} =25°C	0.8	1.3	4.0	
Fall Time*1,*2	t _f		1.4	2.4	6.0	
Turn - on Delay Time ^{*1}	$t_{d(on)}$		ı	0.16	-	
Rise Time*1	t _r	$I_C = 8A, V_{CC} = 300V,$ $V_{GE} = 5V, R_G = 100\Omega,$	ı	0.23	ı	ше
Turn - off Delay Time*1	$t_{d(off)}$	L=5mH, T_j =150°C	I	1.5	ı	μs
Fall Time*1	t _f	,	ı	3.9	1	
Avalanche Energy (Single Pulse)	E _{AS}	$L = 5\text{mH}, V_{GE} = 5V,$ $V_{CC} = 30V, R_G = 1k\Omega,$				
		T _j = 25°C	250	-	-	mJ
		$T_j = 150^{\circ}C^{*2}$	150	-	-	mJ
Gate Series Resistance	R_G		70	100	130	Ω

^{*1)} Assurance items according to our measurement definition (Fig.16)

^{*2)} Design assurance items

Electrical Characteristic Curves

Fig.1 Typical Output Characteristics

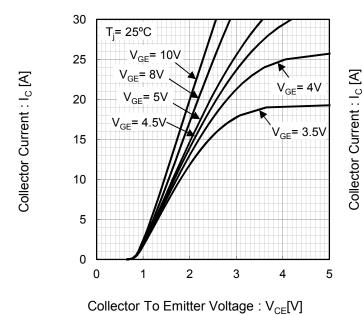
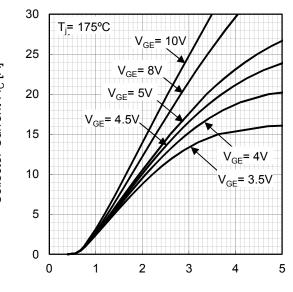


Fig.2 Typical Output Characteristics



Collector To Emitter Voltage : V_{CE}[V]

Fig.3 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

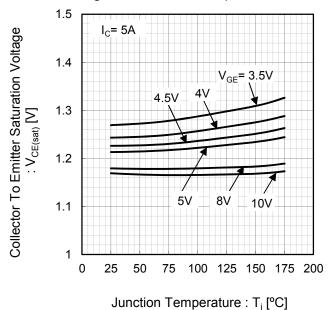
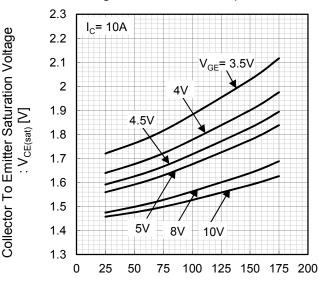


Fig.4 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

Electrical Characteristic Curves

Fig.5 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

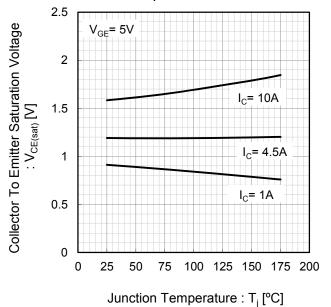
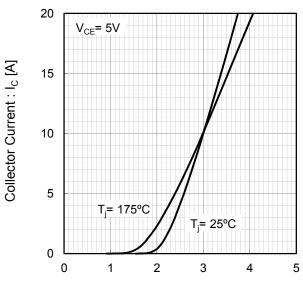


Fig.6 Typical Transfer Characteristics



Gate To Emitter Voltage : V_{GE} [V]

Fig.7 Typical Gate To Emitter Threshold Voltage vs. Junction Temperature

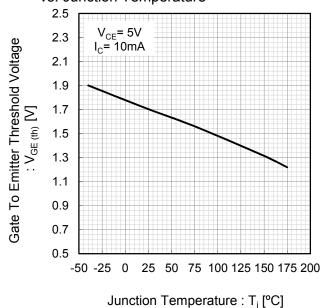
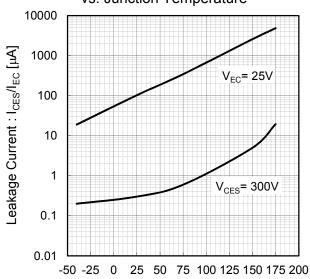


Fig.8 Typical Leakage Current vs. Junction Temperature



Junction Temperature : T_i [°C]

Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Breakdown Voltage vs. Junction Temperature

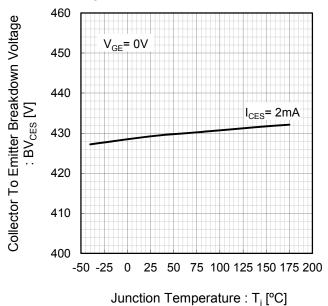


Fig.10 Typical Self Clamped Inductive Switching Current vs. Inductance

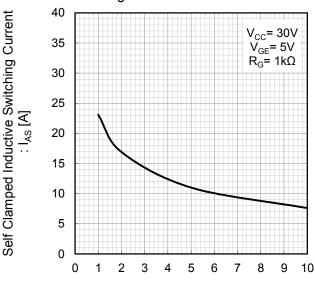


Fig.11 Typical Gate Charge

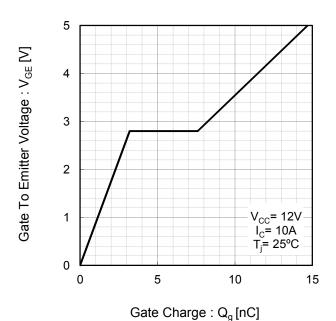
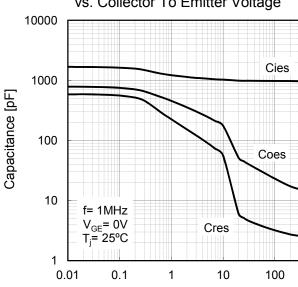


Fig.12 Typical Capacitance vs. Collector To Emitter Voltage

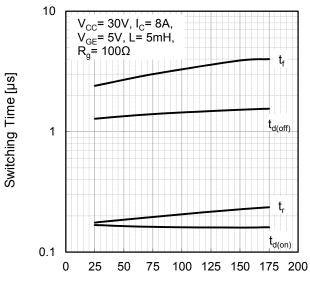
Inductance: L[mH]



Collector To Emitter Voltage : V_{CE}[V]

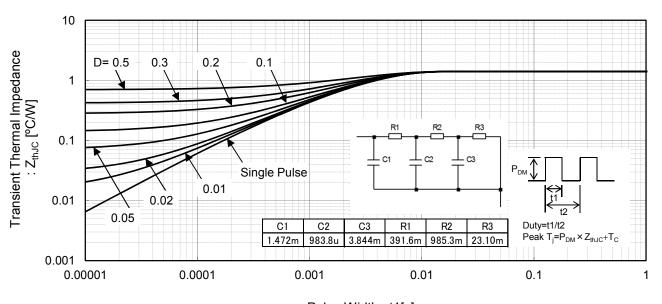
•Electrical Characteristic Curves

Fig.13 Typical Switching Time vs. Junction Temperature



Junction Temperature : T_i [°C]

Fig.14 Transient Thermal Impedance



Pulse Width: t1[s]

•Inductive Load Switching Circuit and Waveform

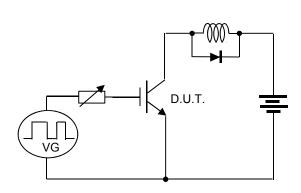


Fig.15 Inductive Load Switching Circuit

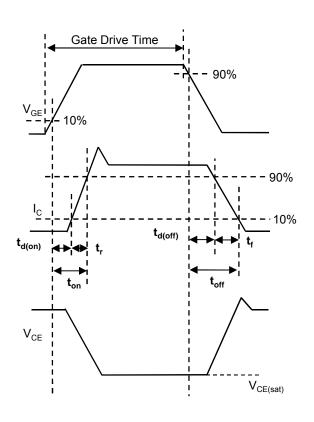
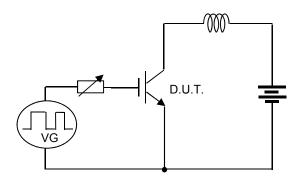


Fig.16 Inductive Load Switching Waveform

● Self Clamped Inductive Switching Circuit and Waveform



 V_{clamp} V_{CC} $V_{CE(sat)}$ E_AS

Fig.17 Self Clamped Inductive Switching Circuit Fig.18 Self Clamped Inductive Switching Waveform

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RGPZ10BM40FH - Web Page

Part Number	RGPZ10BM40FH
Package	TO-252
Unit Quantity	2500
Minimum Package Quantity	2500
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes